



OS12D40

11.3-megapixel product brief

Security Image Sensor Provides Industry-High 11.3MP Resolution for 4K2K With Electronic Image Stabilization and Best in Class HDR for 1080p Video

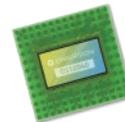
OMNIVISION's OS12D40 is a 1.4 micron pixel, 11.3MP image sensor that offers the unprecedented combination of a large 1/2.49" optical format, on-chip remosaic (4-cell to Bayer) color converter and on-chip high dynamic range (HDR) processing. It is the industry's only security sensor with 3-exposure, 4-cell HDR capability to provide larger-pixel low light performance with the best artifact elimination for moving objects. When in full-HD 1080p mode, this sensor's 3-exposure HDR with on-chip combination and tone mapping provides best in class video captures. This is superior to the competing method, known as staggered HDR, which relies on additional passes that introduce motion artifacts, especially in low light.

Integrated selective conversion gain technology allows the pixel conversion gain to be dynamically switched between low and high, depending on the scene being captured. In combination with its other features—including PureCel®Plus-S stacked pixel technology for reduced cross talk and maximum quantum efficiency in low light—this image sensor enables mass market security cameras to capture the industry's highest quality video and ultra wide angle photos.

The OS12D40's fast mode switch allows security operators or AI-enabled surveillance systems to seamlessly switch to 4K2K mode when a specific threat is identified for closer inspection, such as a potential intruder or unauthorized vehicle. This sensor's best in class 11.3MP resolution provides the extra pixels needed for 4K2K images with electronic image stabilization (EIS), to ensure that details can be clearly identified.

The OS12D40 is a native 16:9 aspect ratio image sensor that uses a 4-cell color filter pattern. It has an on-chip 4-cell to Bayer remosaic converter, in order to provide 4K video at 60 fps with 20% additional pixels for EIS. In a 4-cell binned mode, it can output an impressive 2.8MP/1080p resolution with 20% additional pixels for EIS video and images at four times the sensitivity. This sensor also supports both CPHY and DPHY interfaces.

Find out more at www.ovt.com.



- OS12D40-J08A-001A (color, lead-free)
108-pin fan-out package

Applications

- security cameras
- machine vision
- PC multimedia

Technical Specifications

- active array size:** 4512 x 2512
- maximum image transfer rate:**
 - 4512 x 2512: 60 fps
- power supply:**
 - core: 1.1V
 - analog: 2.8V
 - I/O: 1.8V
- power requirements:**
 - active: 494 mW
 - standby: <10 μ W
- temperature range:**
 - operating: -30°C to +85°C junction temperature
 - stable: 0°C to +60°C junction temperature
- output formats:** 10-bit RGB 4-cell pattern Bayer RAW
- lens size:** 1/2.49"
- lens chief ray angle:** 8.7° linear
- scan mode:** progressive
- pixel size:** 1.404 μ m x 1.404 μ m
- image area:** 6365.736 μ m x 3554.928 μ m

Product Features

- automatic black level calibration (ABLC)
- programmable controls for:
 - frame rate
 - mirror and flip
 - binning
 - cropping
 - windowing
- support for dynamic defect pixel cancellation (DPC)
- supports output formats: 10-bit RGB 4-cell pattern Bayer RAW
- supports horizontal and vertical subsampling
- supports typical images sizes:
 - 4512 x 2512
 - 3840 x 2160
 - 2256 x 1256
 - 1920 x 1080
 - 1280 x 720
- standard serial SCCB interface
- up to 4-lane MIPI TX interface with speed up to 2.5 Gbps/lane
- embedded 8k bits of one-time programmable (OTP) memory (4k bits reserved for customer use)
- 2/3 trio C-PHY interface, up to 1.6 Gbps/trio
- 4-cell support:
 - 4-cell binning
 - 4-cell full
- on-chip 4-cell to Bayer converter
- three on-chip phase lock loops (PLLs)
- sequential multi-frame HDR
- 2.8MP 10-bit 3-exposure 4C HDR output after tone mapping
- programmable I/O drive capability
- built-in temperature sensor
- typical module size: 8.5 x 8.5 x -5.1 mm

Functional Block Diagram

